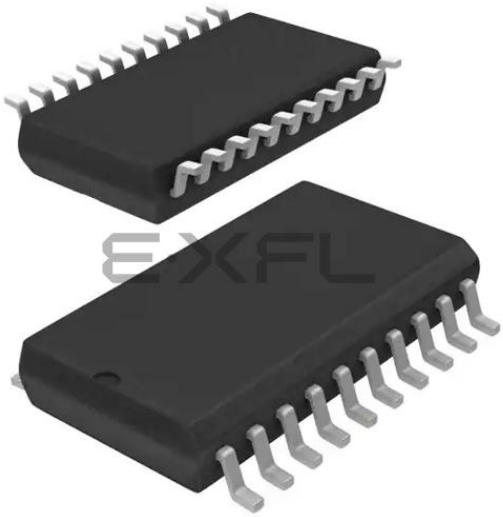

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What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details	
Product Status	Active
Core Processor	STM8
Core Size	8-Bit
Speed	16MHz
Connectivity	I²C, IrDA, LINbus, SPI, UART/USART
Peripherals	Brown-out Detect/Reset, POR, PWM, WDT
Number of I/O	16
Program Memory Size	8KB (8K x 8)
Program Memory Type	FLASH
EEPROM Size	640 x 8
RAM Size	1K x 8
Voltage - Supply (Vcc/Vdd)	2.95V ~ 5.5V
Data Converters	A/D 5x10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 125°C (TA)
Mounting Type	Surface Mount
Package / Case	20-SOIC (0.295", 7.50mm Width)
Supplier Device Package	20-SO
Purchase URL	https://www.e-xfl.com/product-detail/stmicroelectronics/stm8s103f3m3

List of tables

4.6 Power management

For efficient power management, the application can be put in one of four different low-power modes. You can configure each mode to obtain the best compromise between lowest power consumption, fastest start-up time and available wakeup sources.

- **Wait mode:** In this mode, the CPU is stopped, but peripherals are kept running. The wakeup is performed by an internal or external interrupt or reset.
- **Active halt mode with regulator on:** In this mode, the CPU and peripheral clocks are stopped. An internal wakeup is generated at programmable intervals by the auto wake up unit (AWU). The main voltage regulator is kept powered on, so current consumption is higher than in active halt mode with regulator off, but the wakeup time is faster. Wakeup is triggered by the internal AWU interrupt, external interrupt or reset.
- **Active halt mode with regulator off:** This mode is the same as active halt with regulator on, except that the main voltage regulator is powered off, so the wake up time is slower.
- **Halt mode:** In this mode the microcontroller uses the least power. The CPU and peripheral clocks are stopped, the main voltage regulator is powered off. Wakeup is triggered by external event or reset.

4.7 Watchdog timers

The watchdog system is based on two independent timers providing maximum security to the applications.

Activation of the watchdog timers is controlled by option bytes or by software. Once activated, the watchdogs cannot be disabled by the user program without performing a reset.

Window watchdog timer

The window watchdog is used to detect the occurrence of a software fault, usually generated by external interferences or by unexpected logical conditions, which cause the application program to abandon its normal sequence.

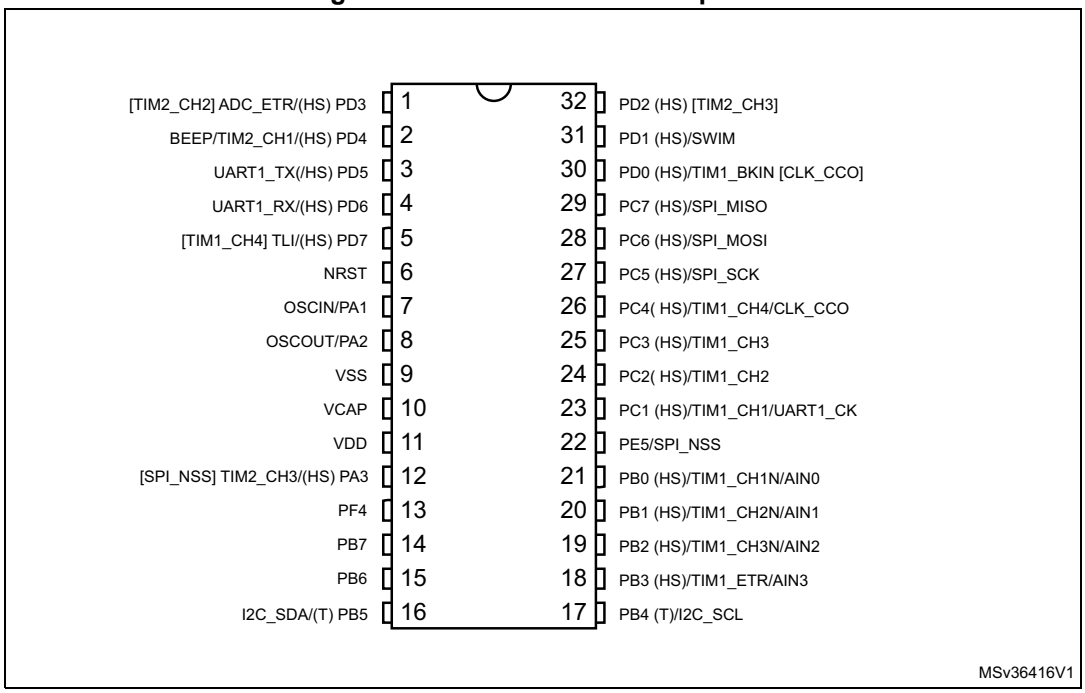
The window function can be used to trim the watchdog behavior to match the application perfectly.

The application software must refresh the counter before time-out and during a limited time window.

A reset is generated in two situations:

1. Timeout: At 16 MHz CPU clock the time-out period can be adjusted between 75 µs up to 64 ms.
2. Refresh out of window: The downcounter is refreshed before its value is lower than the one stored in the window register.

Figure 4. STM8S103K3 SDIP32 pinout



1. (HS) high sink capability.
2. (T) True open drain (P-buffer and protection diode to V_{DD} not implemented).
3. [ ] alternate function remapping option (if the same alternate function is shown twice, it indicates an exclusive choice not a duplication of the function).

Table 5. STM8S103K3 pin descriptions

SDIP32	LQFP/ UFQFP32	Pin name	Type	Input			Output				Main function (after reset)	Default alternate function	Alternate function after remap [option bit]
				floating	wpu	Ext. interrupt	High sink(1)	Speed	OD	PP			
6	1	NRST	I/O	-	**X**	-	-	-	-	-	Reset		-
7	2	PA1/ OSCIN(2)	I/O	**X**	X	X	-	O1	X	X	Port A1	Resonator/ crystal in	-
8	3	PA2/ OSCOUT	I/O	**X**	X	X	-	O1	X	X	Port A2	Resonator/ crystal out	-
9	4	VSS	S	-	-	-	-	-	-	-	Digital ground		-
10	5	VCAP	S	-	-	-	-	-	-		1.8 V regulator capacitor		-
11	6	VDD	S	-	-	-	-	-	-	-	Digital power supply		-
12	7	PA3/ TIM2_CH3 [SPI_NSS]	I/O	**X**	X	X	HS	O3	X	X	Port A3	Timer 2 channel 3	SPI master/ slave select [AFR1]
13	8	PF4	I/O	**X**	X	-	-	O1	X	X	Port F4	-	-
14	9	PB7	I/O	**X**	X	X	-	O1	X	X	Port B7	-	-

Table 6. STM8S103F2 and STM8S103F3 pin descriptions (continued)

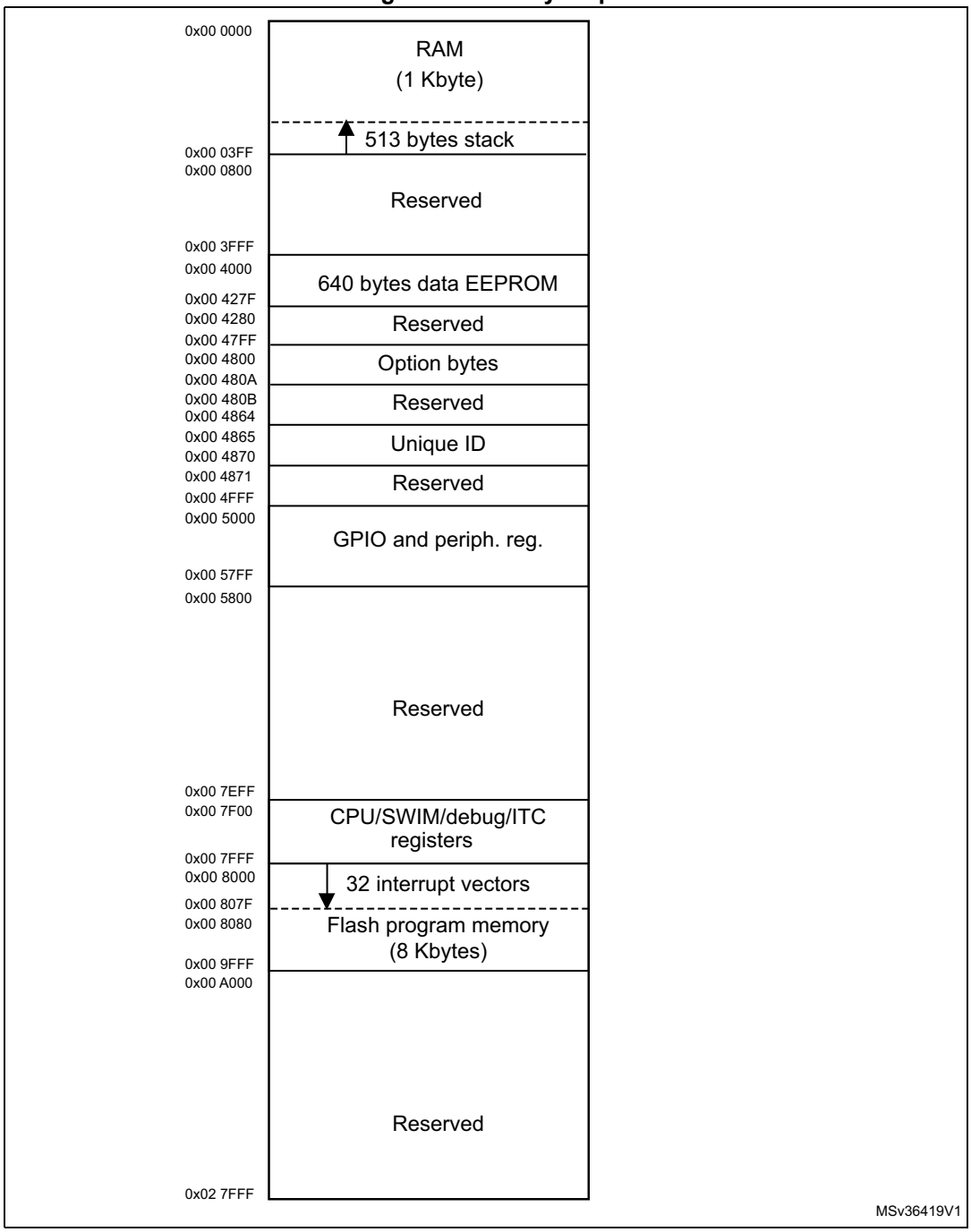
TSSOP/SO20	UFQFPN20	Pin name	Type	Input			Output				Main function (after reset)	Default alternate function	Alternate function after remap [option bit]
				floating	wpu	Ext. interrupt	High sink(1)	Speed	OD	PP			
14	11	PC4/ CLK_CCO/ TIM1_ CH4/AIN2/[TIM1_ CH2N]	I/O	**X**	X	X	HS	O3	X	X	Port C4	Configurable clock output/Timer 1 - channel 4/Analog input 2	Timer 1 - inverted channel 2 [AFR7]
15	12	PC5/ SPI_SCK [TIM2_ CH1]	I/O	**X**	X	X	HS	O3	X	X	Port C5	SPI clock	Timer 2 - channel 1 [AFR0]
16	13	PC6/ SPI_MOSI [TIM1_ CH1]	I/O	**X**	X	X	HS	O3	X	X	Port C6	SPI master out/slave in	Timer 1 - channel 1 [AFR0]
17	14	PC7/ SPI_MISO [TIM1_ CH2]	I/O	**X**	X	X	HS	O3	X	X	Port C7	SPI master in/ slave out	Timer 1 - channel 2 [AFR0]
18	15	PD1/ SWIM	I/O	**X**	X	X	HS	O4	X	X	Port D1	SWIM data interface	-
19	16	PD2/AIN3/[T IM2_ CH3]	I/O	**X**	X	X	HS	O3	X	X	Port D2	Analog input 3	Timer 2 - channel 3 [AFR1]
20	17	PD3/ AIN4/ TIM2_ CH2/ ADC_ ETR	I/O	**X**	X	X	HS	O3	X	X	Port D3	Analog input 4/ Timer 2 - channel 2/ADC external trigger	-

1. I/O pins used simultaneously for high current source/sink must be uniformly spaced around the package. In addition, the total driven current must respect the absolute maximum ratings.
2. When the MCU is in halt/active-halt mode, PA1 is automatically configured in input weak pull-up and cannot be used for waking up the device. In this mode, the output state of PA1 is not driven. It is recommended to use PA1 only in input mode if halt/active-halt is used in the application.
3. In the open-drain output column, “T” defines a true open-drain I/O (P-buffer, weak pull-up, and protection diode to VDD are not implemented).1

6 Memory and register map

6.1 Memory map

Figure 7. Memory map



6.2.2 General hardware register map

Table 8. General hardware register map

Address	Block	Register label	Register name	Reset status
0x00 501E to 0x00 5059	Reserved area (60 byte)			
0x00 505A	Flash	FLASH_CR1	Flash control register 1	0x00
0x00 505B		FLASH_CR2	Flash control register 2	0x00
0x00 505C		FLASH_NCR2	Flash complementary control register 2	0xFF
0x00 505D		FLASH _FPR	Flash protection register	0x00
0x00 505E		FLASH _NFPR	Flash complementary protection register	0xFF
0x00 505F		FLASH _IAPSR	Flash in-application programming status register	0x00
0x00 5060 to 0x00 5061	Reserved area (2 byte)			
0x00 5062	Flash	FLASH _PUKR	Flash program memory unprotection register	0x00
0x00 5063	Reserved area (1 byte)			
0x00 5064	Flash	FLASH _DUKR	Data EEPROM unprotection register	0x00
0x00 5065 to 0x00 509F	Reserved area (59 byte)			
0x00 50A0	ITC	EXTI_CR1	External interrupt control register 1	0x00
0x00 50A1		EXTI_CR2	External interrupt control register 2	0x00
0x00 50A2 to 0x00 50B2	Reserved area (17 byte)			
0x00 50B3	RST	RST_SR	Reset status register	0xXX(1)
0x00 50B4 to 0x00 50BF	Reserved area (12 byte)			
0x00 50C0	CLK	CLK_ICKR	Internal clock control register	0x01
0x00 50C1		CLK_ECKR	External clock control register	0x00
0x00 50C2	Reserved area (1 byte)			

8 Option byte

Option byte contain configurations for device hardware features as well as the memory protection of the device. They are stored in a dedicated block of the memory. Except for the ROP (read-out protection) byte, each option byte has to be stored twice, in a regular form (OPTx) and a complemented one (NOPTx) for redundancy.

Option byte can be modified in ICP mode (via SWIM) by accessing the EEPROM address shown in the table below.

Option byte can also be modified ‘on the fly’ by the application in IAP mode, except the ROP option that can only be modified in ICP mode (via SWIM).

Refer to the STM8S Flash programming manual (PM0051) and STM8 SWIM communication protocol and debug module user manual (UM0470) for information on SWIM programming procedures.

Table 11. Option byte

Addr.	Option name	Option byte no.	Option bits								Factory default setting
			7	6	5	4	3	2	1	0	
0x4800	Read-out protection (ROP)	OPT0	ROP [7:0]								0x00
0x4801	User boot code (UBC)	OPT1	UBC [7:0]								0x00
0x4802		NOPT1	NUBC [7:0]								0xFF
0x4803	Alternate function remapping (AFR)	OPT2	AFR7	AFR6	AFR5	AFR4	AFR3	AFR2	AFR1	AFR0	0x00
0x4804		NOPT2	NAFR7	NAFR6	NAFR5	NAFR4	NAFR3	NAFR2	NAFR1	NAFR0	0xFF
0x4805h	Misc. option	OPT3	Reserved			HSI TRIM	LSI _ EN	IWDG _HW	WWDG _HW	WWDG _HALT	0x00
0x4806		NOPT3	Reserved			NHSI TRIM	NLSI _ EN	NIWDG _HW	NWWDG _HW	NWWG _HALT	0xFF
0x4807	Clock option	OPT4	Reserved				EXT CLK	CKAWU SEL	PRS C1	PRS C0	0x00
0x4808		NOPT4	Reserved				NEXT CLK	NCKA WUSEL	NPRSC1	NPR SC0	0xFF
0x4809	HSE clock startup	OPT5	HSECNT [7:0]								0x00
0x480A		NOPT5	NHSECNT [7:0]								0xFF

Table 12. Option byte description

Option byte no.	Description
OPT0	**ROP[7:0]** Memory readout protection (ROP) 0xAA: Enable readout protection (write access via SWIM protocol) *Note: Refer to the family reference manual (RM0016) section on Flash/EEPROM memory readout protection for details.*
OPT1	**UBC[7:0]** User boot code area 0x00: no UBC, no write-protection 0x01: Page 0 defined as UBC, memory write-protected Page 0 and 1 contain the interrupt vectors. ... 0x7F: Pages 0 to 126 defined as UBC, memory write-protected Other values: Pages 0 to 127 defined as UBC, memory write-protected *Note: Refer to the family reference manual (RM0016) section on Flash write protection for more details.*
OPT2	**AFR[7:0]** Refer to the following section for alternate function remapping descriptions of bits [7:2] and [1:0] respectively.
OPT3	**HSITRIM:** High speed internal clock trimming register size 0: 3-bit trimming supported in CLK_HSITRIMR register 1: 4-bit trimming supported in CLK_HSITRIMR register
	LSI_EN: Low speed internal clock enable 0: LSI clock is not available as CPU clock source 1: LSI clock is available as CPU clock source
	IWDG_HW: Independent watchdog 0: IWDG Independent watchdog activated by software 1: IWDG Independent watchdog activated by hardware
	WWDG_HW: Window watchdog activation 0: WWDG window watchdog activated by software 1: WWDG window watchdog activated by hardware
	WWDG_HALT: Window watchdog reset on halt 0: No reset generated on halt if WWDG active 1: Reset generated on halt if WWDG active

2. Measured from interrupt event to interrupt vector fetch
3. $t_{WU(WFI)} = 2 \times 1/f_{master} + 67 \times 1/f_{CPU}$
4. Configured by the REGAH bit in the CLK_ICKR register.
5. Configured by the AHALT bit in the FLASH_CR1 register.
6. Plus 1 LSI clock depending on synchronization.

Total current consumption and timing in forced reset state

Table 30. Total current consumption and timing in forced reset state

Symbol	Parameter	Conditions	Typ	Max(1)	Unit
$I_{DD(R)}$	Supply current in reset state(2)	V_{DD} = 5 V	400	-	µA
		V_{DD} = 3.3 V	300	-	
$t_{RESETBL}$	Reset pin release to vector fetch	-	-	150	µs

1. Guaranteed by design.
2. Characterized with all I/Os tied to V_{SS}.

Current consumption of on-chip peripherals

Subject to general operating conditions for V_{DD} and T_A.

HSI internal RC/f_{CPU}= f_{MASTER} = 16 MHz, V_{DD} = 5 V

Table 31. Peripheral current consumption

Symbol	Parameter	Typ	Unit
$I_{DD(TIM1)}$	TIM1 supply current(1)	210	µA
$I_{DD(TIM2)}$	TIM2 supply current(1)	130	
$I_{DD(TIM4)}$	TIM4 supply current(1)	50	
$I_{DD(UART1)}$	UART1 supply current (2)	120	
$I_{DD(SPI)}$	SPI supply current (2)	45	
$I_{DD(I2C)}$	I2C supply current(2)	65	
$I_{DD(ADC1)}$	ADC1 supply current when converting(3)	1000	

1. Data based on a differential I_{DD} measurement between reset configuration and timer counter running at 16 MHz. No IC/OC programmed (no I/O pads toggling). Not tested in production.
2. Data based on a differential IDD measurement between the on-chip peripheral when kept under reset and not clocked and the on-chip peripheral when clocked and not kept under reset. No I/O pads toggling. Not tested in production.
3. Data based on a differential IDD measurement between reset configuration and continuous A/D conversions. Not tested in production.

Current consumption curves

The following figures show typical current consumption measured with code executing in RAM.

Figure 16. Typ $I_{DD(WFI)}$ vs. f_{CPU} HSE external clock, V_{DD} = 5 V

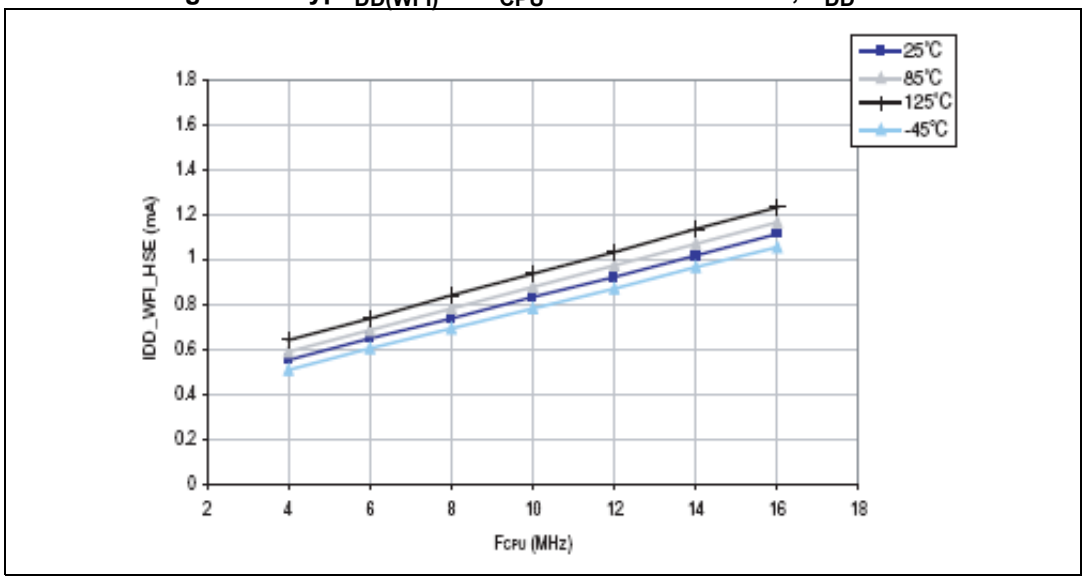
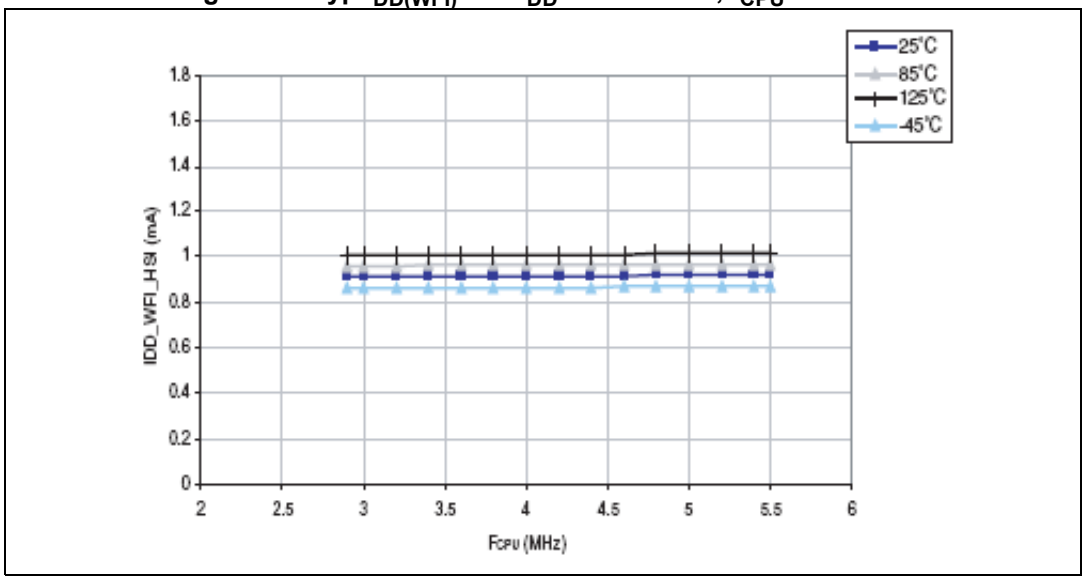


Figure 17. Typ $I_{DD(WFI)}$ vs. V_{DD} HSI RC osc., f_{CPU} = 16 MHz



HSE crystal/ceramic resonator oscillator

The HSE clock can be supplied with a 1 to 16 MHz crystal/ceramic resonator oscillator. All the information given in this paragraph is based on characterization results with specified typical external components. In the application, the resonator and the load capacitors have to be placed as close as possible to the oscillator pins in order to minimize output distortion and startup stabilization time. Refer to the crystal resonator manufacturer for more details (frequency, package, accuracy...).

Table 33. HSE oscillator characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
f_{HSE}	External high speed oscillator frequency	-	1	-	16	MHz
R_F	Feedback resistor	-	-	220	-	kΩ
$C^{(1)}$	Recommended load capacitance(2)	-	-	-	20	pF
$I_{DD(HSE)}$	HSE oscillator power consumption	C = 20 pF f_{OSC} = 16 MHz	-	-	6 (start up) 1.6 (stabilized)(3)	mA
		C = 10 pF f_{OSC} = 16 MHz	-	-	6 (start up) 1.2 (stabilized)(3)	
g_m	Oscillator transconductance	-	5	-	-	mA/V
$t_{SU(HSE)}^{(4)}$	Startup time	V_{DD} is stabilized	-	1	-	ms

1. C is approximately equivalent to 2 x crystal Cload.
2. The oscillator selection can be optimized in terms of supply current using a high quality resonator with small Rm value. Refer to crystal manufacturer for more details
3. Guaranteed by characterization results.
4. $t_{SU(HSE)}$ is the start-up time measured from the moment it is enabled (by software) to a stabilized 16 MHz oscillation is reached. This value is measured for a standard crystal resonator and it can vary significantly with the crystal manufacturer.

10.3.6 I/O port pin characteristics

General characteristics

Subject to general operating conditions for V_{DD} and T_A unless otherwise specified. All unused pins must be kept at a fixed voltage, using the output mode of the I/O for example or an external pull-up or pull-down resistor.

Table 38. I/O static characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{IL}	Input low level voltage	V_{DD} = 5 V	-0.3 V	-	0.3 x V_{DD}	V
V_{IH}	Input high level voltage		0.7 x V_{DD}	-	V_{DD} + 0.3 V	
V_{hys}	Hysteresis(1)		-	700	-	mV
R_{pu}	Pull-up resistor	V_{DD} = 5 V, V_{IN} = V_{SS}	30	55	80	kΩ
t_R, t_F	Rise and fall time (10% - 90%)	Fast I/Os Load = 50 pF	-	-	35(2)	ns
		Standard and high sink I/Os Load = 50 pF	-	-	125(2)	
t_R, t_F	Rise and fall time (10% - 90%)	Fast I/Os Load = 20 pF	-	-	20(2)	ns
		Standard and high sink I/Os Load = 20 pF	-	-	50(2)	
I_{lkg}	Digital input leakage current	$V_{SS} \leq V_{IN} \leq V_{DD}$	-	-	±1(3)	µA
$I_{lkg\ ana}$	Analog input leakage current	$V_{SS} \leq V_{IN} \leq V_{DD}$	-	-	±250(3)	nA
$I_{lkg(inj)}$	Leakage current in adjacent I/O	Injection current ±4 mA	-	-	±1(3)	µA

1. Hysteresis voltage between Schmitt trigger switching levels. Based on characterization results, not tested in production.
2. Data guaranteed by design.
3. Guaranteed by characterization results

Table 40. Output driving current (true open drain ports)

Symbol	Parameter	Conditions	Min	Max	Unit
V_{OL}	Output low level with 2 pins sunk	I_{IO}= 10 mA, V_{DD} = 5 V	-	1.0	V
	Output low level with 2 pins sunk	I_{IO}= 10 mA, V_{DD} = 3.3 V	-	1.5(1)	
V_{OH}	Output high level with 2 pins sourced	I_{IO}= 10 mA, V_{DD} = 5 V	-	2.0(1)	

1. Guaranteed by characterization results

Table 41. Output driving current (high sink ports)

Symbol	Parameter	Conditions	Min	Max	Unit
V_{OL}	Output low level with 8 pins sunk	I_{IO}= 10 mA, V_{DD} = 5 V	-	0.8	V
	Output low level with 4 pins sunk	I_{IO}= 10 mA, V_{DD} = 3.3 V	-	1.0(1)	
		I_{IO}= 20 mA, V_{DD} = 5 V	-	1.5(1)	
V_{OH}	Output high level with 8 pins sourced	I_{IO}= 10 mA, V_{DD} = 5 V	4.0	-	
	Output high level with 4 pins sourced	I_{IO}= 10 mA, V_{DD} = 3.3 V	2.1(1)	-	
		I_{IO}= 20 mA, V_{DD} = 5 V	3.3(1)	-	

1. Guaranteed by characterization results.

Figure 25. Typ. V_{OL} @ V_{DD} = 3.3 V (standard ports)

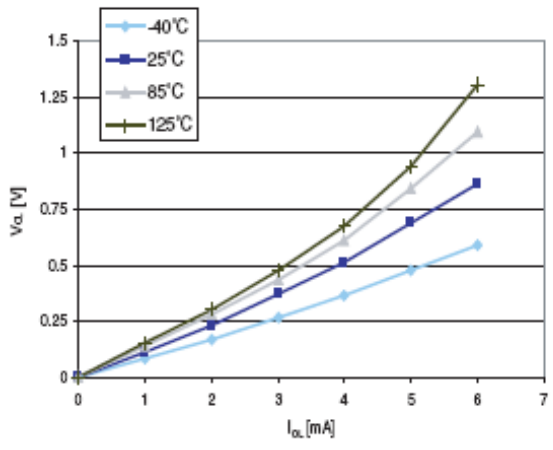


Figure 26. Typ. V_{OL} @ V_{DD} = 5.0 V (standard ports)

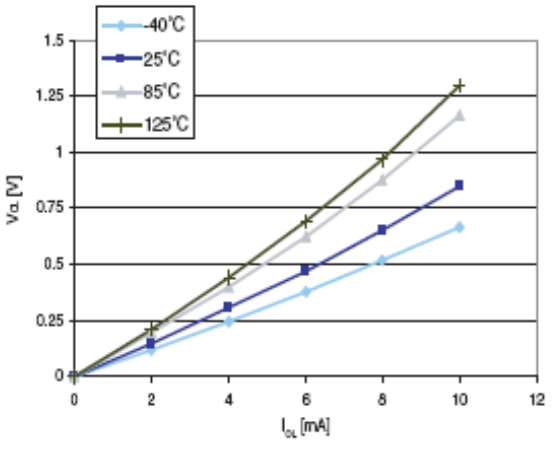


Figure 31. Typ. V_{DD} - V_{OH} @ V_{DD} = 3.3 V (standard ports)

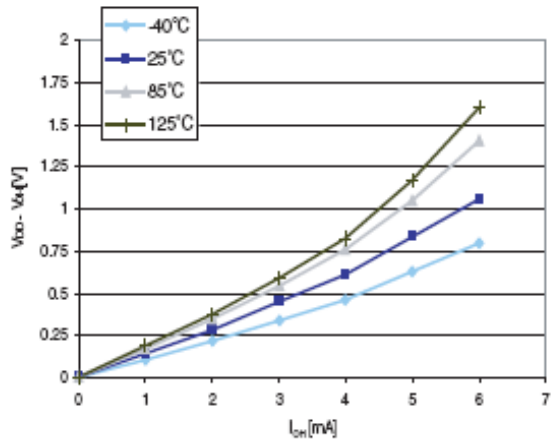


Figure 32. Typ. V_{DD} - V_{OH} @ V_{DD} = 5.0 V (standard ports)

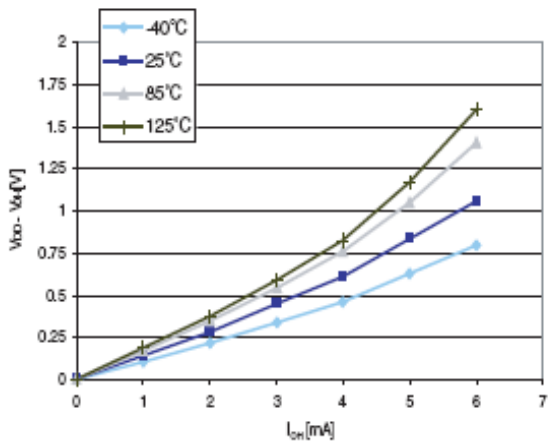


Figure 33. Typ. V_{DD} - V_{OH} @ V_{DD} = 3.3 V (high sink ports)

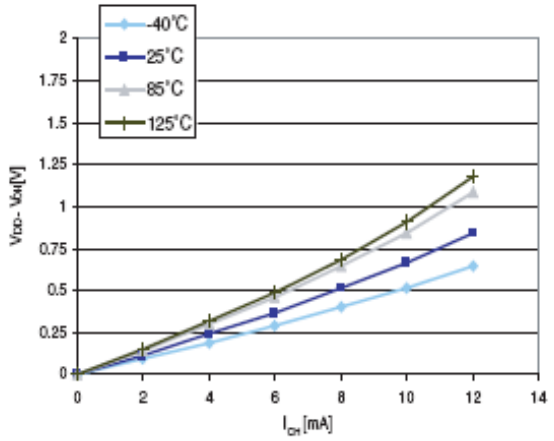


Figure 34. Typ. V_{DD} - V_{OH} @ V_{DD} = 5.0 V (high sink ports)

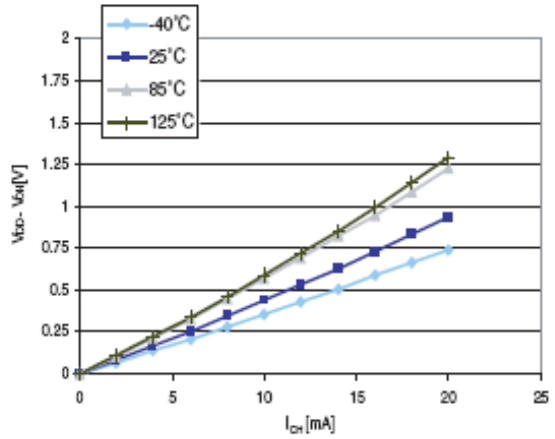


Table 46. ADC accuracy with R_{AIN}< 10 kΩ, V_{DD}= 5 V

Symbol	Parameter	Conditions	Typ	Max(1)	Unit
$\|E_T\|$	Total unadjusted error(2)	f_{ADC} = 2 MHz	1.6	3.5	LSB
		f_{ADC} = 4 MHz	2.2	4	
		f_{ADC} = 6 MHz	2.4	4.5	
$\|E_O\|$	Offset error(2)	f_{ADC} = 2 MHz	1.1	2.5	
		f_{ADC} = 4 MHz	1.5	3	
		f_{ADC} = 6 MHz	1.8	3	
$\|E_G\|$	Gain error(2)	f_{ADC} = 2 MHz	1.5	3	
		f_{ADC} = 4 MHz	2.1	3	
		f_{ADC} = 6 MHz	2.2	4	
$\|E_D\|$	Differential linearity error(2)	f_{ADC} = 2 MHz	0.7	1.5	
		f_{ADC} = 4 MHz	0.7	1.5	
		f_{ADC} = 6 MHz	0.7	1.5	
$\|E_L\|$	Integral linearity error(2)	f_{ADC} = 2 MHz	0.6	1.5	
		f_{ADC} = 4 MHz	0.8	2	
		f_{ADC} = 6 MHz	0.8	2	

1. Guaranteed by characterization results.
2. ADC accuracy vs. negative injection current: Injecting negative current on any of the analog input pins should be avoided as this significantly reduces the accuracy of the conversion being performed on another analog input. It is recommended to add a Schottky diode (pin to ground) to standard analog pins which may potentially inject negative current. Any positive injection current within the limits specified for $I_{INJ(PIN)}$ and $\Sigma I_{INJ(PIN)}$ in *Section 10.3.6* does not affect the ADC accuracy.

This test conforms to the EIA/JESD 78 IC latch-up standard. For more details, refer to the application note AN1181.

Table 51. Electrical sensitivities

Symbol	Parameter	Conditions	Class(1)
LU	Static latch-up class	T_A = 25 °C	A
		T_A = 85 °C	
		T_A = 125 °C	

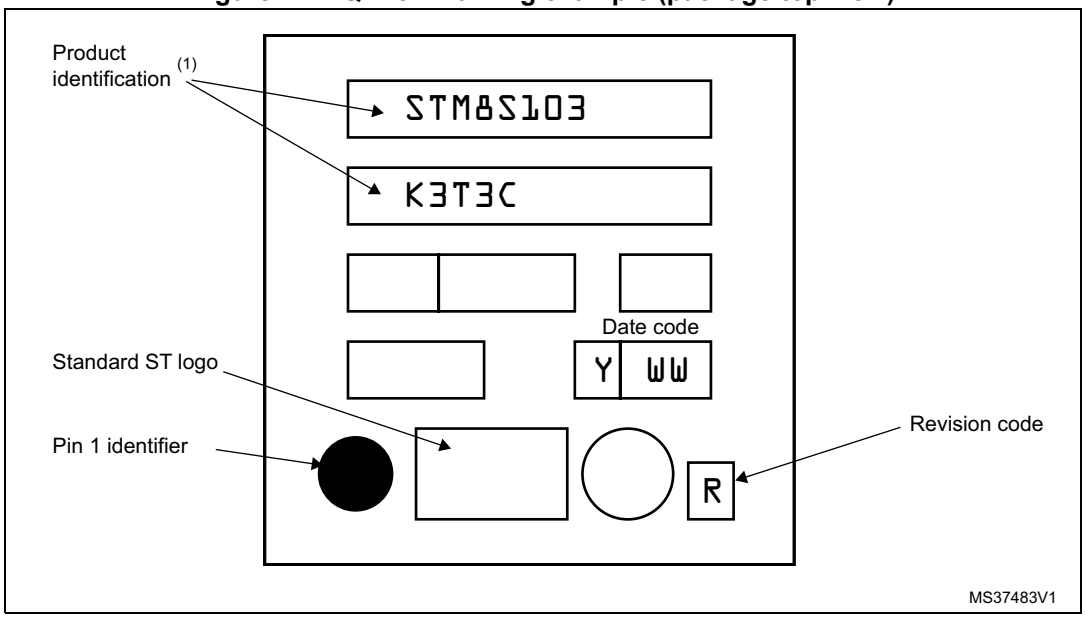
1. Class description: A Class is an STMicroelectronics internal specification. All its limits are higher than the JEDEC specifications, that means when a device belongs to class A it exceeds the JEDEC standard. B class strictly covers all the JEDEC criteria (international standard).

Device marking

The following figure gives an example of topside marking orientation versus pin 1 identifier location.

Other optional marking or inset/upset marks, which identify the parts throughout supply chain operations, are not indicated below.

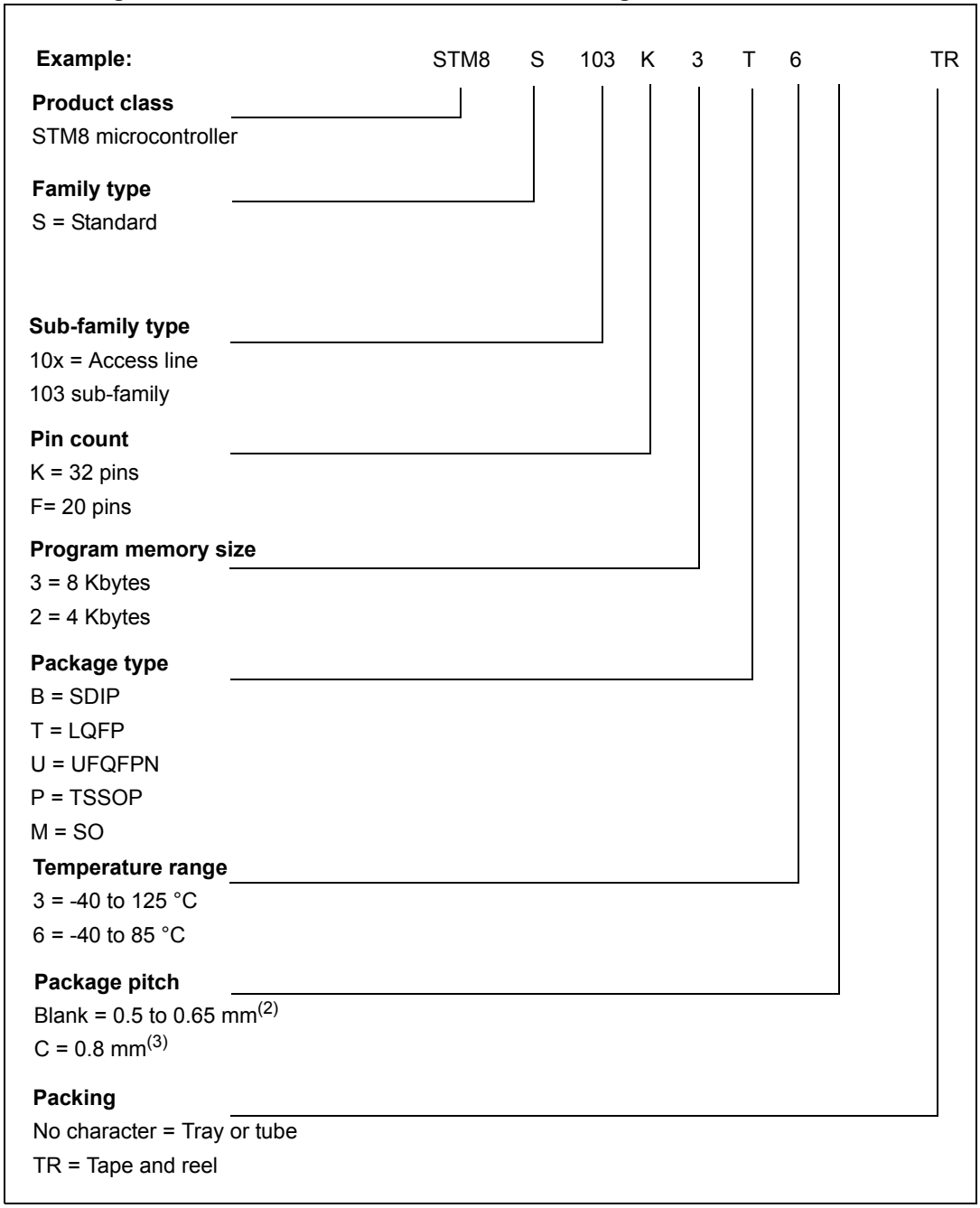
Figure 47. LQFP32 marking example (package top view)



1. Parts marked as “ES”,”E” or accompanied by an Engineering Sample notification letter, are not yet qualified and therefore not yet ready to be used in production and any consequences deriving from such usage will not be at ST charge. In no event, ST will be liable for any customer usage of these engineering samples in production. ST Quality has to be contacted prior to any decision to use these Engineering samples to run qualification activity.

13 Ordering information

Figure 63. STM8S103F2/x3 access line ordering information scheme(1)



1. A dedicated ordering information scheme will be released if, in the future, memory programming service (FastROM) is required The letter “P” will be added after STM8S. Three unique letters identifying the customer application code will also be visible in the codification. Example: STM8SP103K3MACTR.
2. UFQFPN, TSSOP, and SO packages.
3. LQFP package.

For a list of available options (for example memory size, package) and orderable part numbers or for further information on any aspect of this device, please go to *www.st.com* or contact the ST Sales Office nearest to you.

13.1 STM8S103 FASTROM microcontroller option list

(last update: April 2010)

Customer	.....
Address	.....
Contact	.....
Phone number	.....
FASTROM code reference(1)	.....

1. The FASTROM code name is assigned by STMicroelectronics.

The preferable format for programing code is .hex (.s19 is accepted)

If data EEPROM programing is required, a separate file must be sent with the requested data.

Note: See the option byte section in the datasheet for authorized option byte combinations and a detailed explanation. Do not use more than one remapping option in the same port. It is forbidden to enable both AFR1 and AFR0.

Device type/memory size/package (check only one option)

FASTROM device	4 Kbyte	8 Kbyte
LQFP32	-	[ ] STM8S103K3
UFQFPN20	[ ] STM8S103F2	[ ] STM8S103F3
UFQFPN32	-	[ ] STM8S103K3
TSSOP20	[ ] STM8S103F2	[ ] STM8S103F3
SO20W	[ ] STM8S103F2	[ ] STM8S103F3

Conditioning (check only one option)

[ ] Tape and reel or [ ] Tray

Special marking (check only one option)

[ ] No [ ] Yes

Authorized characters are letters, digits, '.', '-', '/' and spaces only. Maximum character counts are:

UFQFPN20: 1 line of 4 characters max: “_ _ _ _”

UFQFPN32: 1 line of 7 characters max: “_ _ _ _ _ _ _”

LQFP32: 2 lines of 7 characters max: “_ _ _ _ _ _ _” and “_ _ _ _ _ _ _”

TSSOP20/SO20: 1 line of 10 characters max: “_ _ _ _ _ _ _ _ _ _”

Three characters are reserved for code identification.